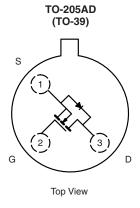
## 2N6660, 2N6660-2, 2N6660JANTX, 2N6660JANTXV

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## N-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	60				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	3				
Configuration	Single				



#### **FEATURES**

- · Military Qualified
- Low On-Resistence: 1.3  $\Omega$
- Low Threshold: 1.7 V
- Low Input Capacitance: 35 pF
- Fast Switching Speed: 8 ns
- Low Input and Output Leakage

### **BENEFITS**

- Guaranteed Reliability
- Low Offset Voltage
- Low-Voltage Operation
- Easily Driven Without Buffer
- High-Speed Circuits
- Low Error Voltage

#### **APPLICATIONS**

- Hi-Rel Systems
- Direct Logic-Level Interface: TTL/CMOS
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.
- · Battery Operated Systems
- Solid-State Relays

ORDERING INFORMATION					
PART	PACKAGE	DESCRIPTION/DSCC PART NUMBER	VISHAY ORDERING PART NUMBER		
2N6660		Commercial	2N6660		
	TO-205AD (TO-39)	Commercial, Lead (Pb)-free	2N6660-E3		
2N6660-2		See -2 Flow Document	2N6660-2		
2N6660JANTX		JANTX2N6660 (std Au leads)	2N6660JTX02		
		JANTX2N6660 (with solder)	2N6660JTXL02		
		JANTX2N6660P (with PIND)	2N6660JTXP02		
2N6660JANTXV		JANTXV2N6660 (std Au leads)	2N6660JTXV02		
		JANTXV2N6660P (with PIND)	2N6660JTVP02		

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	LIMIT	UNIT			
Drain-Source Voltage		V <sub>DS</sub>	60	V		
Gate-Source Voltage	V <sub>GS</sub>	± 20	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \			
Continuous Drain Current (T <sub>J</sub> = 150 °C)	T <sub>C</sub> = 25 °C	I <sub>D</sub>	0.99			
	T <sub>C</sub> = 100 °C	o d	0.62	Α		
Pulsed Drain Current <sup>a</sup>	I <sub>DM</sub>	3				
Maximum Power Dissipation	T <sub>C</sub> = 25 °C	В	6.25	10/		
	T <sub>A</sub> = 25 °C	P <sub>D</sub>	0.725	W		
Thermal Resistance, Junction-to-Ambient <sup>b</sup>		R <sub>thJA</sub>	170	°C/W		
Thermal Resistance, Junction-to-Case	R <sub>thJC</sub>	20				
Operating Junction and Storage Temperature R	ange	T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C		

#### Notes

- a. Pulse width limited by maximum junction temperature.
- b. Not required by military spec.



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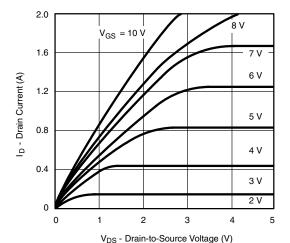
<b>SPECIFICATIONS</b> (T <sub>A</sub> = 25 °C, unless otherwise noted)								
					LIMITS			
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.a	MAX.	UNIT	
Static								
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{DS} = 0 \text{ V}, I_{D} = 10 \mu\text{A}$		60	75	ı		
		$V_{DS} = V_{GS}$ , $I_D = 1 \text{ mA}$		0.8	1.7	2	v	
Gate-Source Threshold Voltage	$V_{GS(th)}$	T <sub>C</sub> = - 55 °C		T <sub>C</sub> = - 55 °C	-	-	2.5	V
				T <sub>C</sub> = 125 °C	0.3	-	ı	
Gate-Body Leakage	1	V+20V	$V_{DS}$	= 0 V	-	-	± 100	- A
Gale-body Leakage	I <sub>GSS</sub>	$V_{GS} = \pm 20 \text{ V}$	T <sub>C</sub> = 125 °C	-	-	± 500	nA	
Zara Cata Valtaga Drain Current	_	V - 0 V	V <sub>DS</sub> =	= 48 V	-	-	1	
Zero Gate Voltage Drain Current	o Gate Voltage Drain Current $I_{DSS}$ $V_{GS} = 0 \text{ V}$		T <sub>C</sub> = 125 °C	-	-	100	μA	
On-State Drain Current	I <sub>D(on)</sub>	V <sub>GS</sub> = 10 V	V <sub>DS</sub> = 10 V		-	2	-	Α
		V <sub>GS</sub> = 5 V	I <sub>D</sub> = 0.3 A		-	2	5	
Drain-Source On-State Resistance <sup>b</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V	I <sub>D</sub> = 1 A		-	1.3	3	Ω
			GS = 10 V	T <sub>C</sub> = 125 °C	-	2.4	5.6	
Forward Transconductanceb	9 <sub>fs</sub>	$V_{DS} = 7.5 \text{ V}, I_D = 0.525 \text{ A}$		170	350	-	mS	
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> = 0.99 A, V <sub>GS</sub> = 0 V		0.7	0.8	1.6	V	
Dynamic								
Input Capacitance	C <sub>iss</sub>					35	50	- pF
Output Capacitance	Coss	V 0V	= 0 V V <sub>DS</sub> = 25 V, f = 1 MHz		-	25	40	
Reverse Transfer Capacitance	C <sub>rss</sub>	$V_{GS} = 0 V$			-	7	10	
Drain-Source Capacitance	C <sub>ds</sub>				_	30	-	
Switching <sup>c</sup>								
Turn-On Time	t <sub>ON</sub>	$V_{DD} = 25 \text{ V}, \text{ R}_L = 23 \ \Omega$ $I_D \cong 1 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_g = 25 \ \Omega$		-	8	10	no	
Turn-Off Time	t <sub>OFF</sub>			-	8.5	10	ns	

### Notes

- a. FOR DESIGN AID ONLY, not subject to production testing.
- b. Pulse test: PW  $\leq$  300  $\mu$ s duty cycle  $\leq$  2 %.
- c. Switching time is essentially independent of operating temperature.

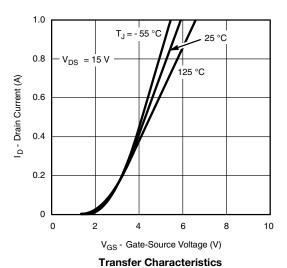
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



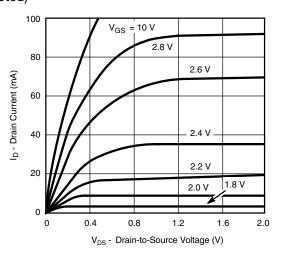
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**Ohmic Region Characteristics** 

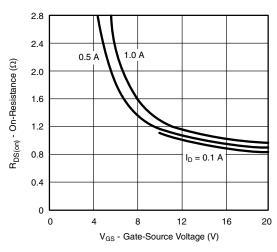


On-Resistance vs. Drain Current

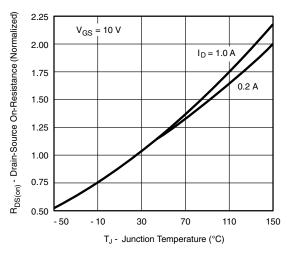
2.5



**Output Characteristics for Low Gate Drive** 



On-Resistance vs. Gate-to-Source Voltage

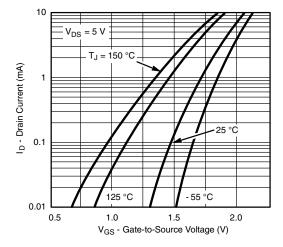


Normalized On-Resistance vs. Junction Temperature

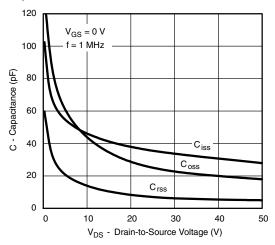
# 2N6660, 2N6660-2, 2N6660JANTX, 2N6660JANTXV

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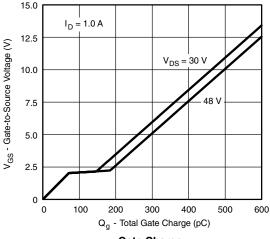
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



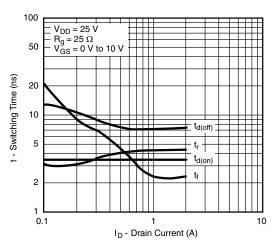
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#### **Threshold Region**

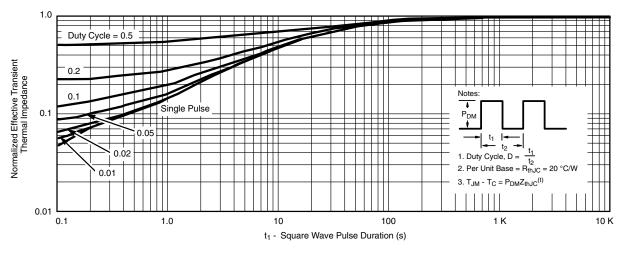


Capacitance



#### Gate Charge



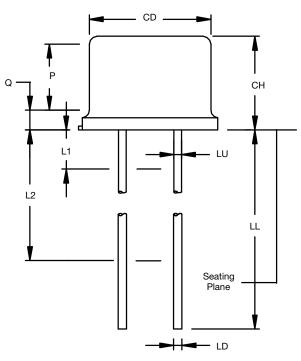


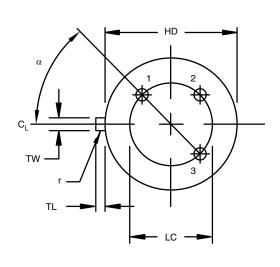
Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="https://www.vishay.com/ppg270223">www.vishay.com/ppg270223</a>.



## **TO-205AD (TO-39 TALL LID)**





DIM.	INCH	IES	MILLIMETERS		
	MIN.	MAX.	MIN.	MAX.	
CD	0.305	0.335	7.75	8.51	
CH	0.240	0.260	6.10	6.60	
HD	0.335	0.370	8.51	9.40	
LC <sup>(6)</sup>	0.200	) TP	5.08	3 TP	
LD <sup>(7)(8)</sup>	0.016	0.021	0.41	0.53	
LL (7)(8)	0.500	0.750	12.70	19.05	
LU (7)(8)	0.016	0.019	0.41	0.48	
L1 <sup>(7)(8)</sup>	_	0.050	_	1.27	
L2 <sup>(7)(8)</sup>	0.250	_	6.35	_	
P (5)	0.100	_	2.54	_	
Q <sup>(4)</sup>	_	0.050	_	1.27	
r <sup>(9)</sup>	_	0.010	_	0.25	
TL <sup>(3)</sup>	0.029	0.045	0.74	1.14	
TW <sup>(2)</sup>	0.028	0.034	0.71	0.86	
α (6)	45° TP		45°	TP	

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DWG: 5511

#### Notes

- (1) Dimensions are in inches. Metric equivalents are given for general information only.
- (2) Beyond radius (r) maximum, TW shall be held for a minimum length of 0.011" (0.028 mm).
- (3) Dimension TL measured from maximum HD.
- (4) Outline in this zone is not controlled.
- (5) Dimension CD shall not vary more than 0.010 (0.25 mm) in zone P. This zone is controlled for automatic handling.
- (6) Leads at guage plane 0.054" + 0.001", 0.000" (1.37 mm + 0.03 mm, 0.00 mm) below seating plane shall be within 0.007" (0.18 mm) radius of true position (TP) at maximum material condition (MMC) relative to tab at MMC.
- (7) LU applies between L1 and L2, LD applies between L2 and L maximum. Diameter is uncontrolled in L1 and beyond LL minimum.
- (8) All three leads.
- (9) Radius (r) applies to both inside corners of tab.
- $^{(10)}$  Drain is electrically connected to the case.

Revison: 27-Jul-15 1 Document Number: 71367



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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Revision: 02-Oct-12 Document Number: 91000